



# AMP1004 SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all modulations standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	1.0 - 2.0 GHz	
Power Output	250 Watt Min	CW
Power Gain	12 dB Min	
Power Gain Flatness	2.0 dB p-p Max	Constant input power
Input / Output Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30dBc Typ	44 dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	>20 dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc	
Operating Voltage	28 - 30 VDC	
Current Consumption	25 Amp Max	At rated Pout
Max Input Power	20 Watt Max	Without damage
Load VSWR Protection	$\infty : 1$	
Turn On / Off Speed	5 $\mu\text{Sec}$ Max	

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	220 x 146 x 27 mm	Excluding Connectors
Weight	TBD	Max Weight
RF Connectors In/Out	SMA female / Type-N Female	
DC Power / Interface Connector	7 Pin Hybrid D-Sub	
Cooling	External Heatsink	Forced air required

## D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	N/C	
2	N/C	
3	CURRENT SENSOR	$I_D @ 10\text{mV}/100\text{mA}$ Typ
4	TEMP SENSOR	$V_T @ 10\text{mV}/^\circ\text{C} + 500\text{mV}$ Typ
5	SHUTDOWN	TTL
A1	VDD	28VDC
A2	GND	Ground

## OUTLINE DRAWING

